

L603 - L604

DARLINGTON ARRAYS

- EIGHT DARLINGTONS PER PACKAGE
- OUTPUT CURRENT 400 mA PER DRIVER (500mA PEAK)
- OUTPUT VOLTAGE 90 V (V_{CE (sus)}) = 70 V)
- INTEGRAL SUPPRESSION DIODES FOR INDUCTIVE LOADS
- OUTPUTS CAN BE PARALLELED FOR HIGHER CURRENT
- TTL / CMOS INPUTS
- INPUTS PINNED OPPOSITE OUTPUTS TO SIMPLIFY LAYOUT

DESCRIPTION

The L603 and L604 are high voltage, high current darlington arrays each containing eight open collector darlington pairs with common emitter: Each channel is rated at 400mA and can with stand peak currents of 500 mA.

Suppression diodes are included for ir ductive load driving and the inputs are pinned opposite the outputs to simplify board lavour

The four versions intenace to all common logic families:

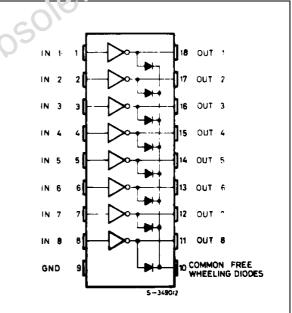
L603 = 5V T1'. L604 = 5 15V CMOS

These versatile devices are useful for driving a vice range of loads, including solenoids, relays

wice range of loads, including solenoids, relays DC motors, LED displays, filament lamps, thermal printheads and high power buffers.



PIN CONNECTION (top view)



Symbol	Parameter	Value	Unit
V _{CEX}	Collector Emitter Voltage (input open)	90	V
Ι _C	Collector Current	0.4	Α
Ic	Collector Peak Current	0.5	A
Vi	Input Voltage (for L603 and L604)	30	V
P _{tot}	Total Power Dissipation a T _{amb} = 25°C	1.8	W
T _{op}	Operating Junction Temperature	-25 to 150	°C

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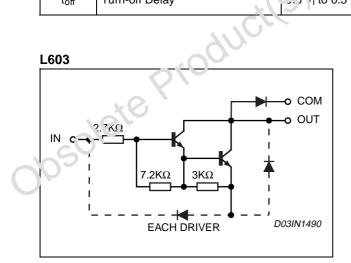
ABSOLUTE MAXIMUM RATINGS

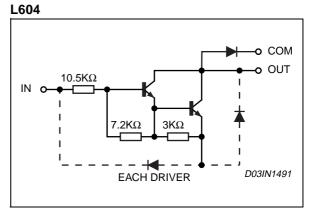
THERMAL DATA

Symbol	Parameter	Value	Unit
R _{th-j amb}	Thermal Resistance Junction ambient	max 70	°C/W

ELECTRICAL CHARACTERISTCS

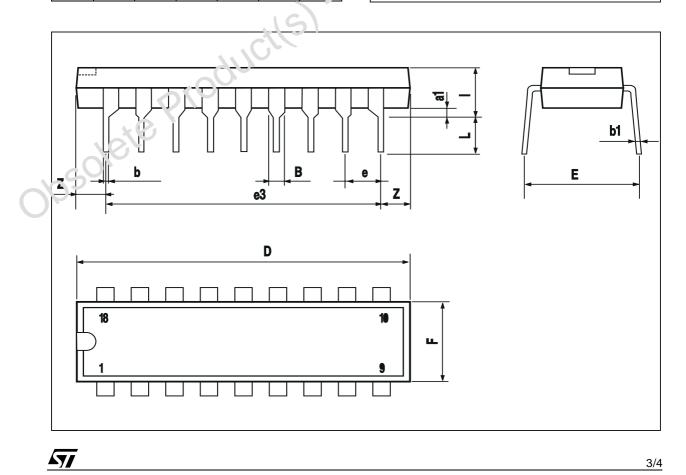
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I _{CEX}	Output Leakage Current	V _{CE} = 90V			10	μΑ
V _{CE(sat)}	Collector Emitter Saturation	I _C = 300mA; I _B = 500μA			2	V
	Voltage	$I_{C} = 200 \text{mA}; I_{B} = \mu \text{A}$			1.7	v
		I _C = 100mA; I _B = 250μA			1 2	V
Vi	Maximum Input Voltage (ON condition)	V _{CE} = 3V; I _C = 300mA L603 L604	20		2.5 5	V V
Vi	Maximum Input Voltage (OFF condition)	V _{CE} = 90V; I _C = 25µA L603 L604	0.75			V V
I _R	Clamp Diode Reverse Current	V _R = 90V			50	μΑ
VF	Clamp Diode Forward Voltage	I _F = 300mA		2	2.4	V
t _{on}	Turn-on Delay	0.5 V _i to 0.5 V _o		0.4		μs
t _{off}	Turn-off Delay	2.5 / _i to 0.5 V _o		0.4		μΑ





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OUTLINE AND		inch		mm inch		mm			mm		DIM.
MECHANICAL DATA	MAX.	TYP.	MIN.	MAX.	TYP.	MIN.					
			0.010			0.254	a1				
	0.065		0.055	1.65		1.39	В				
		0.018			0.46		b				
		0.010			0.25		b1				
	0.915			23.24			D				
		0.335			8.5		Е				
		0.100			2.54		е				
0100		0.800			20.32		e3				
×0 [×]	0.280			7.1			F				
101-	0.155			3.93			Ι				
		0.130			3.3		L				
DIP18	0.063	0.050		1.59	1.27		Z				



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